

## 1. General description

Planar passivated SCR with sensitive gate in a SOT223 surface mountable plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

## 2. Features and benefits

- On-state RMS current, 1.25 A
- Repetitive peak off-state voltage, 1000 V
- High surge current capability
- Direct triggering from low power drivers and logic ICs
- Planar passivated for voltage ruggedness and reliability
- Surface mountable package

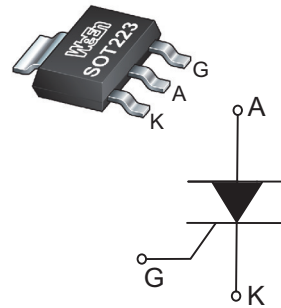
## 3. Applications

- GFCI (Ground Fault Circuit Interrupter)
- AFCI (Arc Fault Circuit Interrupter)
- RCD (Residual Current Device)
- RCBO (Residual Current circuit Breaker with Overload protection)
- AFDD (Arc Fault Detection Device)

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Values	Unit
$V_{DRM}, V_{RRM}$	1000	V
$I_{T(RMS)}$	1.25	A
$I_{GT}$	≤90	μA
$T_j$	125	°C



## 5. Characteristics

**Table 2. Limiting values**
*In accordance with the Absolute Maximum Rating System (IEC 60134).*

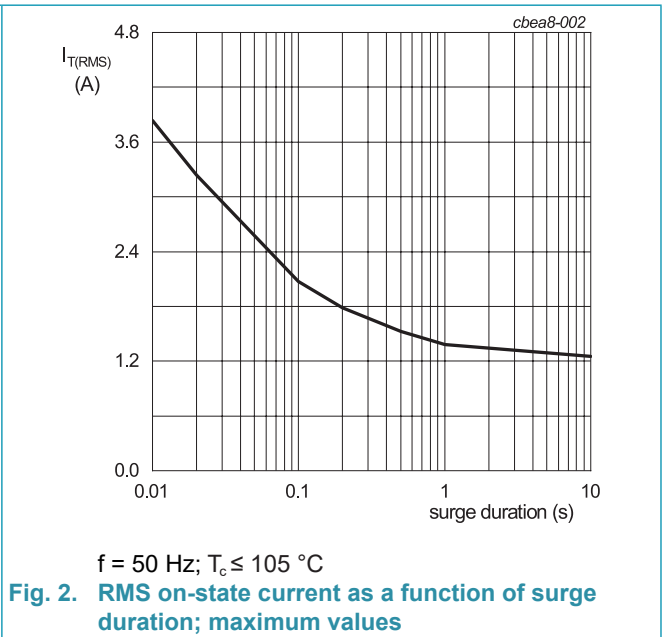
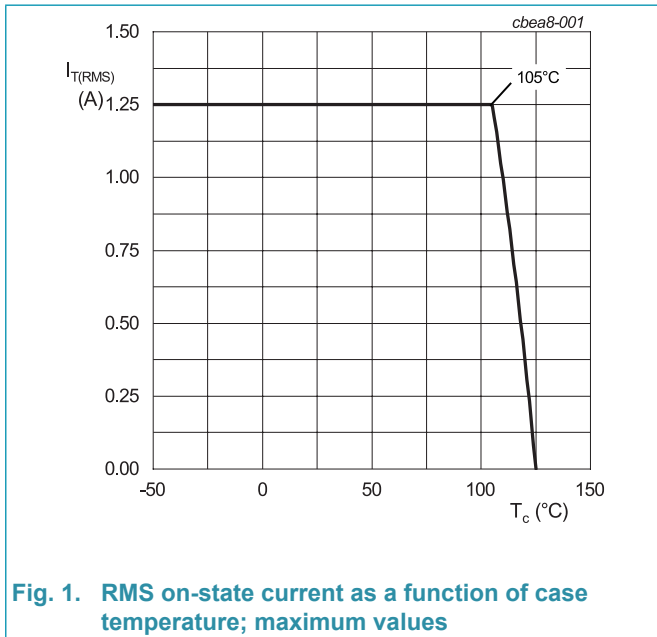
Symbol	Parameter	Conditions	Values	Unit
$V_{DRM}$	repetitive peak off-state voltage		1000	V
$V_{RRM}$	repetitive peak reverse voltage		1000	V
$I_{T(AV)}$	average on-state current	half sine wave; $T_c \leq 105\text{ °C}$	0.8	A
$I_{T(RMS)}$	RMS on-state current	half sine wave; $T_c \leq 105\text{ °C}$	1.25	A
$I_{TSM}$	non-repetitive peak on-state current	half sine wave; $T_{j(\text{init})} = 25\text{ °C}$ ; $t_p = 10\text{ ms}$	23	A
		half sine wave; $T_{j(\text{init})} = 25\text{ °C}$ ; $t_p = 8.3\text{ ms}$	25	A
$I^2t$	$I^2t$ for fusing	$t_p = 10\text{ ms}$ ; sine-wave pulse	2.645	$A^2s$
$di_T/dt$	rate of rise of on-state current	$I_G = 0.1\text{ mA}$	100	$A/\mu s$
$I_{GM}$	peak gate current		1.2	A
$P_{GM}$	peak gate power		2	W
$P_{G(AV)}$	average gate power	over any 20 ms period	0.2	W
$T_{stg}$	storage temperature		-40 to 150	$^{\circ}\text{C}$
$T_j$	junction temperature		-40 to 125	$^{\circ}\text{C}$

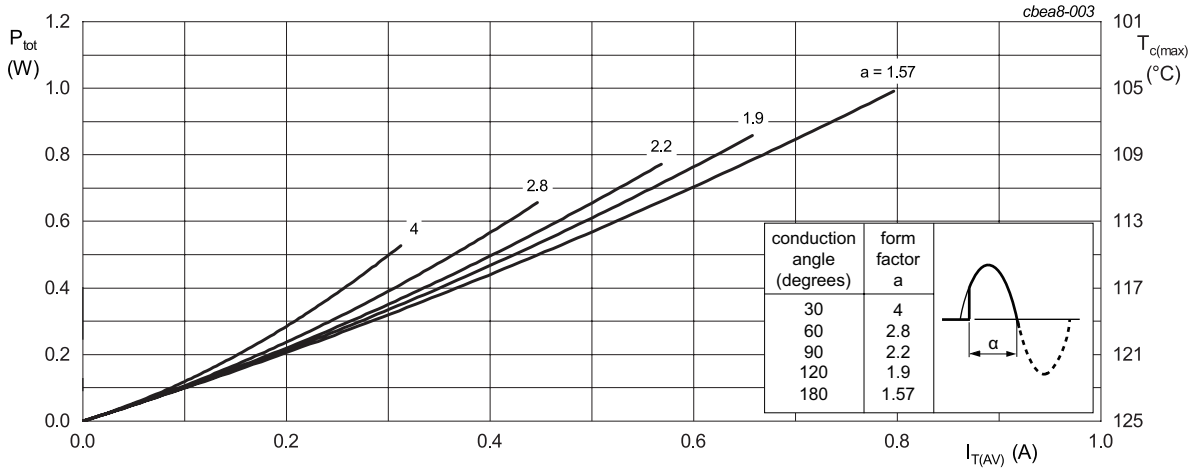
**Table 3. Electrical Characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$I_{GT}$	gate trigger current	$V_D = 12\text{ V}$ ; $R_L = 100\ \Omega$ ; $T_j = 25\text{ °C}$	10	-	90	$\mu\text{A}$
$V_{GT}$	gate trigger voltage	$V_D = 12\text{ V}$ ; $R_L = 100\ \Omega$ ; $T_j = 25\text{ °C}$	-	0.6	0.8	V
		$V_D = 800\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 125\text{ °C}$	0.25	0.4	-	V
$V_{RG}$	gate reverse voltage	$I_{RG} = 2\text{ mA}$	10	-	-	V
$I_L$	latching current	$I_T = 0.1\text{ A}$ ; $R_{GK} = 1\text{ k}\Omega$ ; $T_j = 25\text{ °C}$	-	-	5	mA
$I_H$	holding current	$V_D = 12\text{ V}$ ; $R_{GK} = 1\text{ k}\Omega$ ; $T_j = 25\text{ °C}$	-	-	3	mA
$V_T$	on-state voltage	$I_T = 2.5\text{ A}$ ; $T_j = 25\text{ °C}$	-	-	1.45	V
$I_{DRM}$	off-state current	$V_D = V_{DRM} / V_{RRM}$ ; $R_{GK} = 1\text{ k}\Omega$				$T_j = 25\text{ °C}$
$I_{RRM}$	reverse current					$T_j = 125\text{ °C}$
<b>Dynamic characteristics</b>						
$dV_D/dt$	rate of rise of off-state voltage	$V_{DM} = 670\text{ V}$ ; $T_j = 125\text{ °C}$ ; $R_{GK} = 1\text{ k}\Omega$ ; ( $V_{DM} = 67\%$ of $V_{DRM}$ ); exponential waveform	50	-	-	$V/\mu s$

Table 4. Thermal characteristics

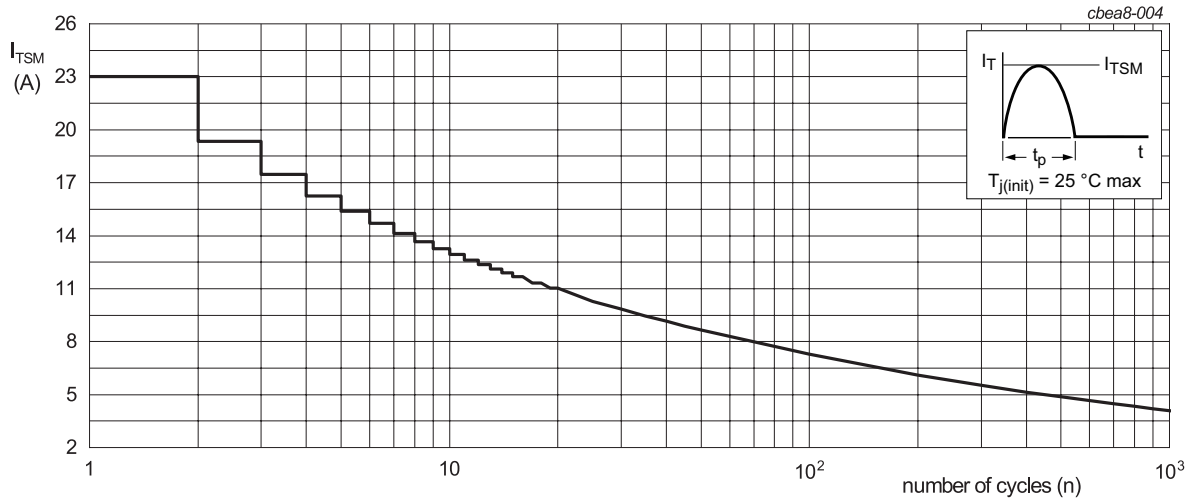
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-c)}$	thermal resistance from junction to case		SOT223	-	-	20	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	SOT223	-	120	-	K/W





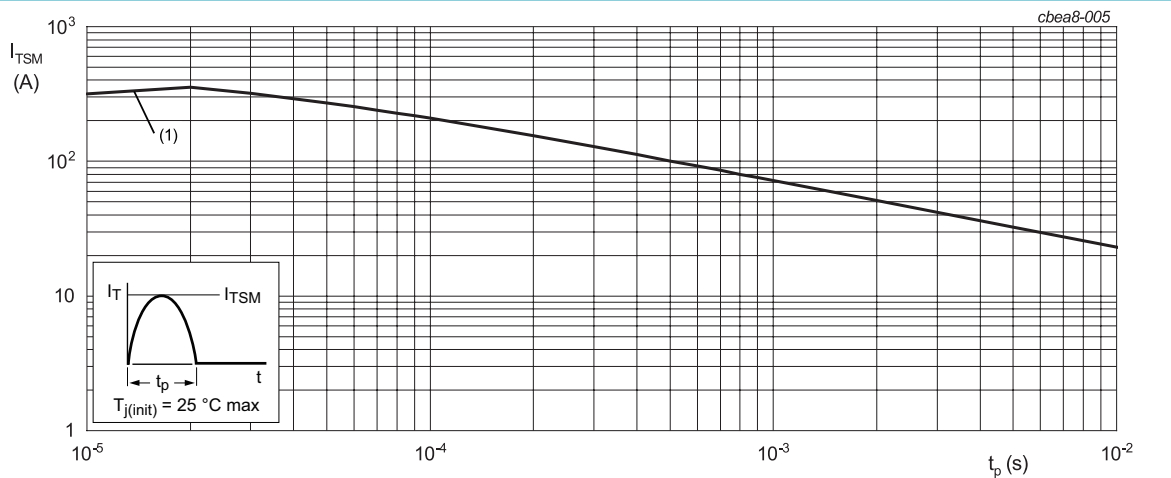
$\alpha$  = conduction angle  
 $a$  = form factor =  $I_{T(RMS)} / I_{T(AV)}$

Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values



$f = 50 \text{ Hz}$

Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



$t_p \leq 10 \text{ ms}$   
 (1)  $di_T/dt$  limit

Fig. 5. Non-repetitive peak on-state current as a function of pulse duration; maximum values

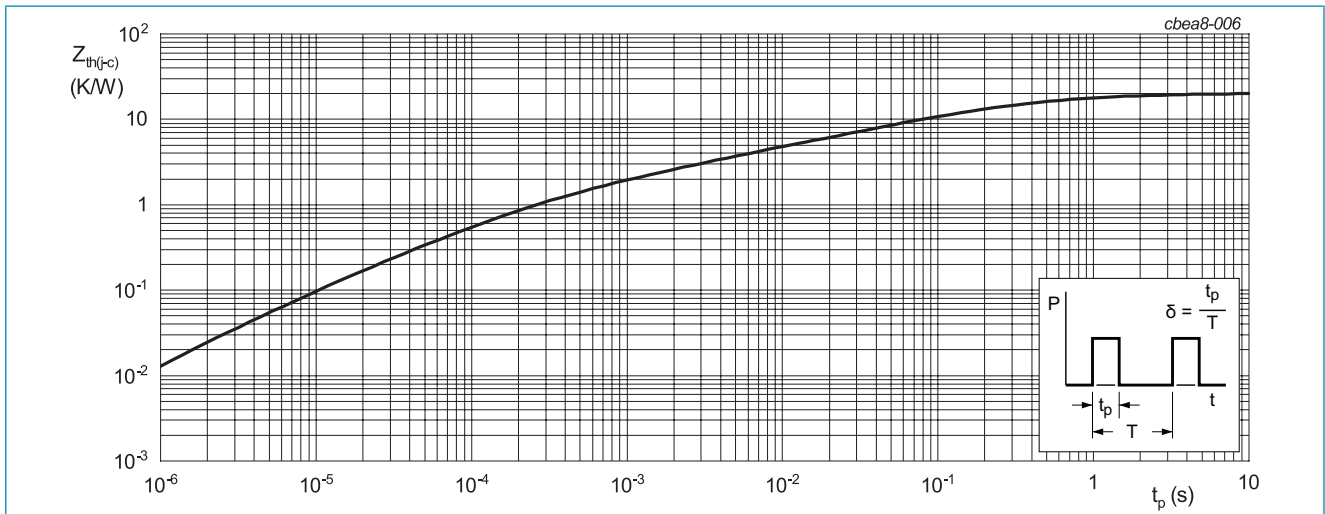


Fig. 6. Transient thermal impedance from junction to case as a function of pulse duration

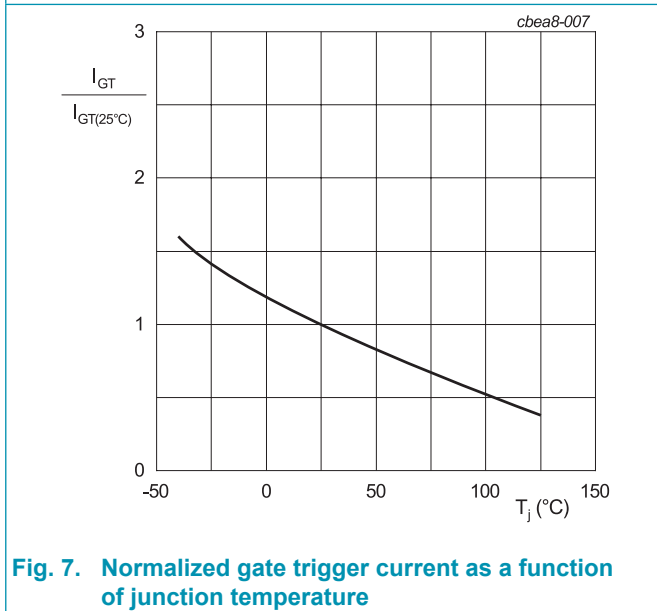


Fig. 7. Normalized gate trigger current as a function of junction temperature

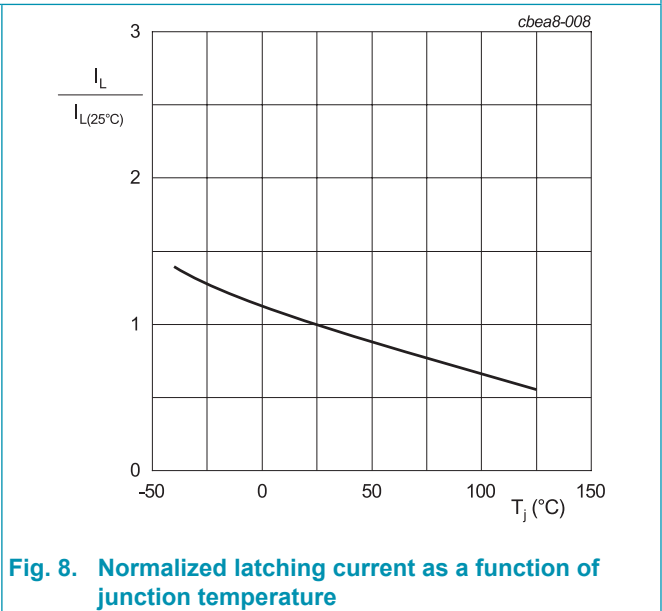
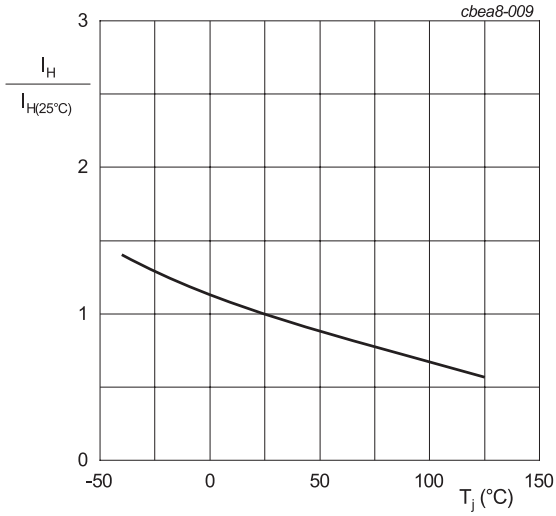
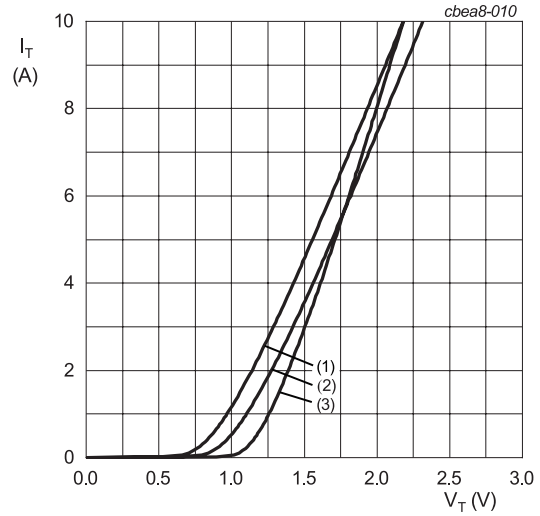


Fig. 8. Normalized latching current as a function of junction temperature

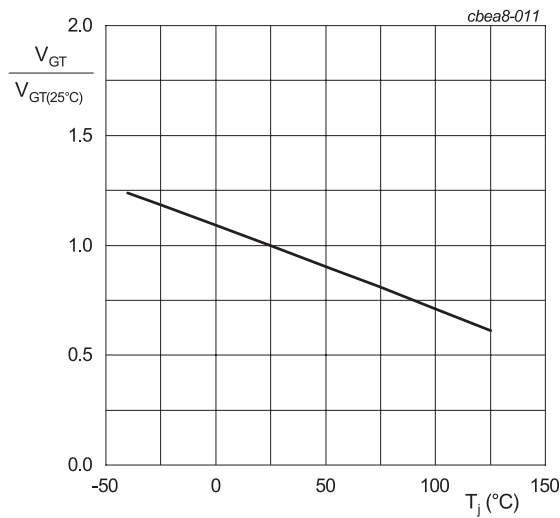


**Fig. 9. Normalized holding current as a function of junction temperature**



$V_o = 0.957 \text{ V}; R_s = 0.1464 \ \Omega$   
 (1)  $T_j = 150 \ ^\circ\text{C}$ ; typical values  
 (2)  $T_j = 150 \ ^\circ\text{C}$ ; maximum values  
 (3)  $T_j = 25 \ ^\circ\text{C}$ ; maximum values

**Fig. 10. On-state current as a function of on-state voltage**



**Fig. 11. Normalized gate trigger voltage as a function of junction temperature**

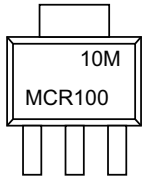
## 6. Ordering information

Table 5. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
MCR100W-10M	SOT223		Reel	1000	SOT223	16-Mar-2006

## 7. Marking

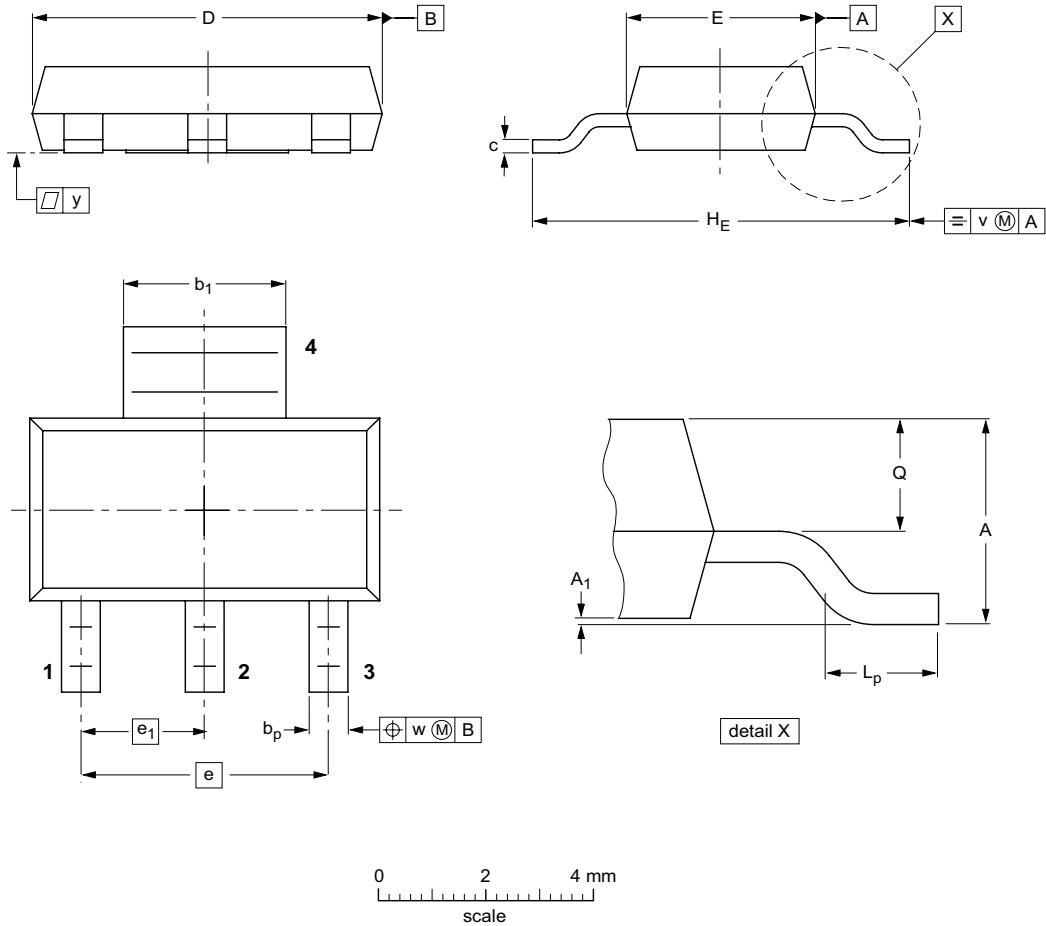
Table 6. Marking codes

Type number	Marking codes
MCR100W-10M	 A schematic diagram of a 3-pin SOT223 package. The package is rectangular with a small tab at the top. It has three pins extending downwards. The marking codes '10M' and 'MCR100' are shown on the top surface of the package.

### 8. Package outline

Plastic surface-mounted package with increased heatsink; 4 leads

SOT223



DIMENSIONS (mm are the original dimensions)

UNIT	A	A <sub>1</sub>	b <sub>p</sub>	b <sub>1</sub>	c	D	E	e	e <sub>1</sub>	H <sub>E</sub>	L <sub>p</sub>	Q	v	w	y
mm	1.8 1.5	0.10 0.01	0.80 0.60	3.1 2.9	0.32 0.22	6.7 6.3	3.7 3.3	4.6	2.3	7.3 6.7	1.1 0.7	0.95 0.85	0.2	0.1	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT223			SC-73			04-11-10 06-03-16



## 9. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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